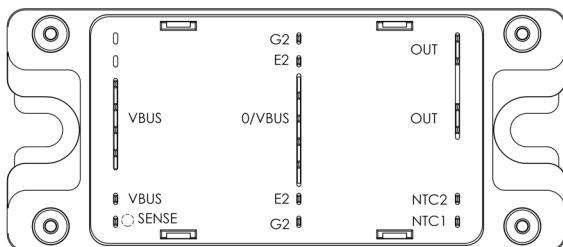
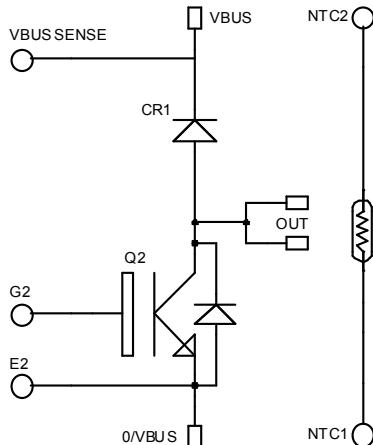


**Boost chopper
Fast Trench + Field Stop IGBT3
Power Module**

**V_{CES} = 1200V
I_C = 75A @ T_c = 80°C**



Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V _{CES}	Collector - Emitter Breakdown Voltage	1200	V
I _C	Continuous Collector Current	T _c = 25°C	A
		T _c = 80°C	
I _{CM}	Pulsed Collector Current	T _c = 25°C	
V _{GE}	Gate – Emitter Voltage	±20	V
P _D	Maximum Power Dissipation	T _c = 25°C	W
RBSOA	Reverse Bias Safe Operating Area	T _j = 125°C	150A @ 1150V

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Fast Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration
- Internal thermistor for temperature monitoring

Benefits

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0\text{V}$, $V_{CE} = 1200\text{V}$	$T_j = 25^\circ\text{C}$	1.4	1.7	2.1	μA
$V_{CE(\text{sat})}$	Collector Emitter saturation Voltage						
$V_{GE(\text{th})}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$	$I_C = 3\text{ mA}$	5.0		6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20\text{V}$	$V_{CE} = 0\text{V}$			400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0\text{V}$	$V_{CE} = 25\text{V}$	5340			pF
C_{oes}	Output Capacitance						
C_{res}	Reverse Transfer Capacitance						
$T_{d(on)}$	Turn-on Delay Time	$V_{GE} = \pm 15\text{V}$	$V_{Bus} = 600\text{V}$	260			ns
T_r	Rise Time						
$T_{d(off)}$	Turn-off Delay Time						
T_f	Fall Time						
$T_{d(on)}$	Turn-on Delay Time	$V_{GE} = \pm 15\text{V}$	$V_{Bus} = 600\text{V}$	285			ns
T_r	Rise Time						
$T_{d(off)}$	Turn-off Delay Time						
T_f	Fall Time						
E_{on}	Turn-on Switching Energy	$V_{GE} = \pm 15\text{V}$	$T_j = 125^\circ\text{C}$	7			mJ
E_{off}	Turn-off Switching Energy						

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage	$V_R = 1200\text{V}$	$T_j = 25^\circ\text{C}$	1200			V
I_{RM}	Maximum Reverse Leakage Current						
I_F	DC Forward Current		$T_c = 80^\circ\text{C}$	75			A
V_F	Diode Forward Voltage	$I_F = 75\text{A}$	$T_j = 25^\circ\text{C}$	1.5	2.0		V
t_{rr}	Reverse Recovery Time						
Q_{rr}	Reverse Recovery Charge	$I_F = 75\text{A}$ $V_R = 600\text{V}$ $di/dt = 2000\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$	7			μC
E_r	Reverse Recovery Energy						
			$T_j = 125^\circ\text{C}$	13.5			
			$T_j = 25^\circ\text{C}$	3.7			
			$T_j = 125^\circ\text{C}$	7.2			

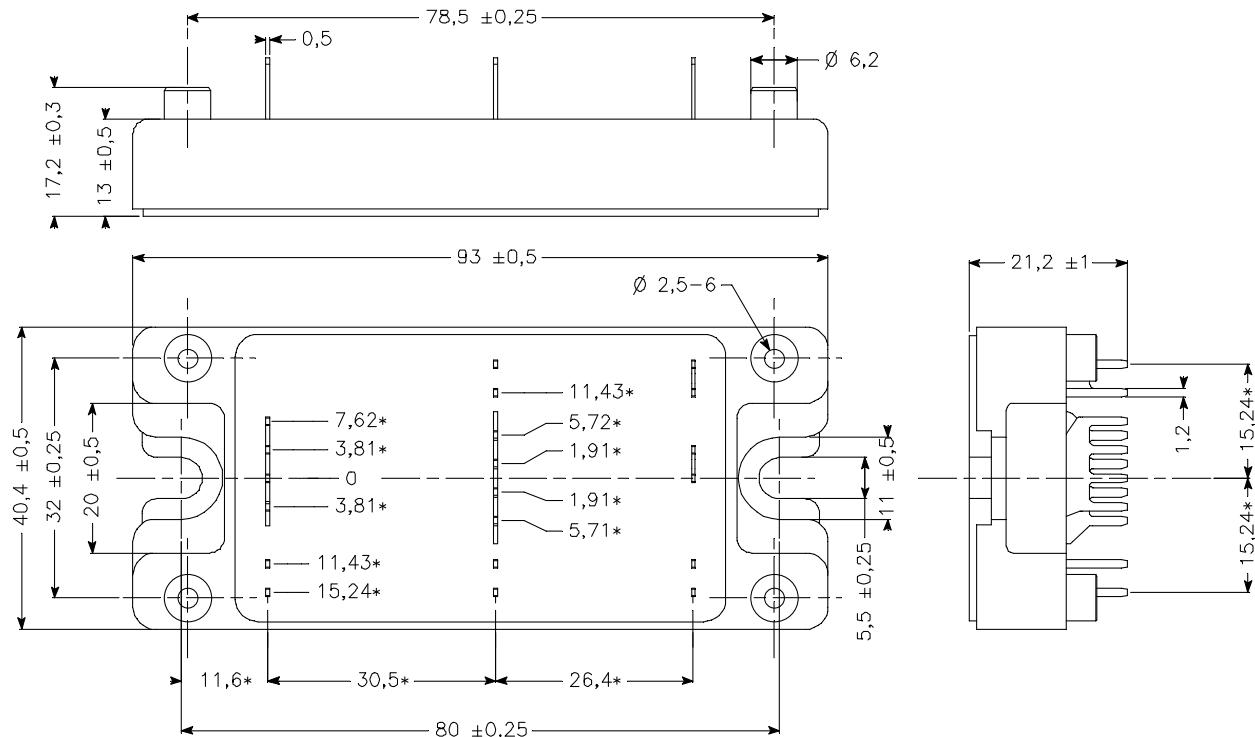
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

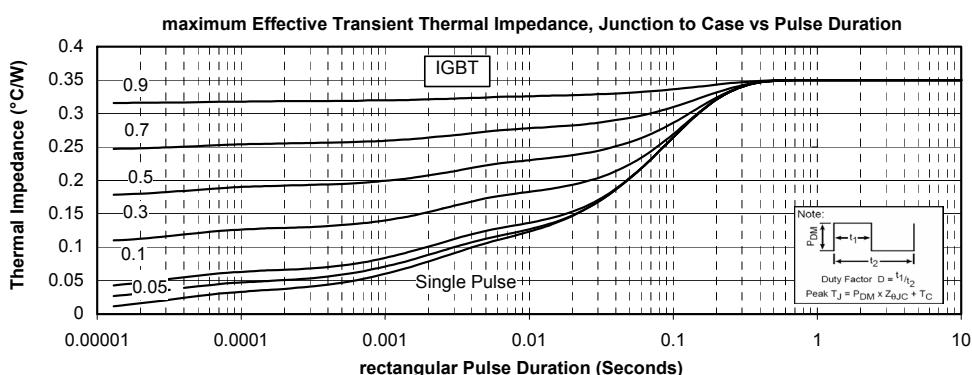
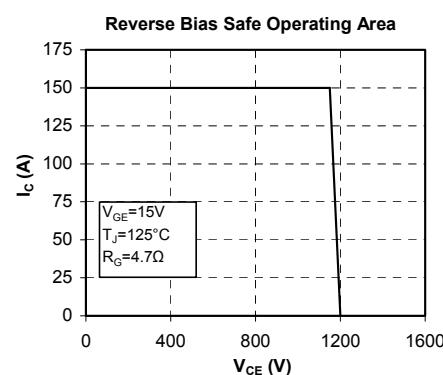
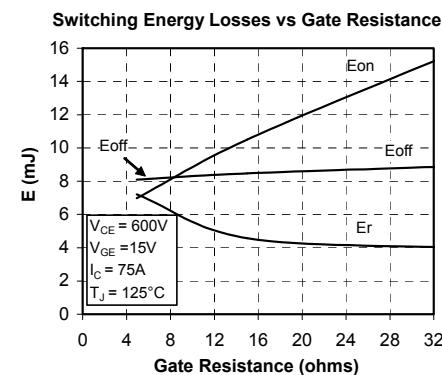
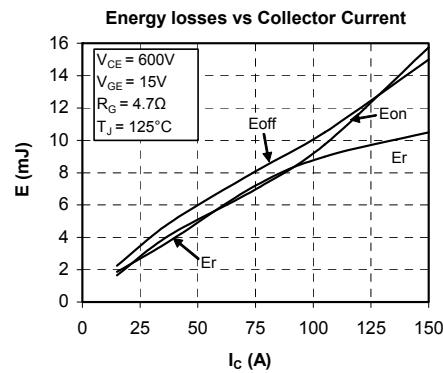
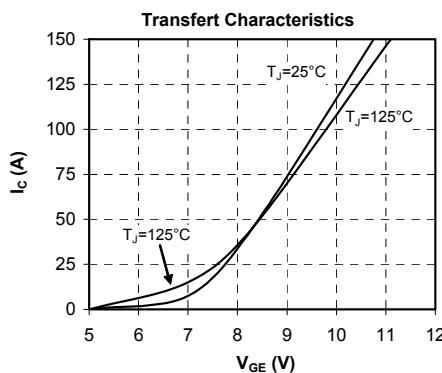
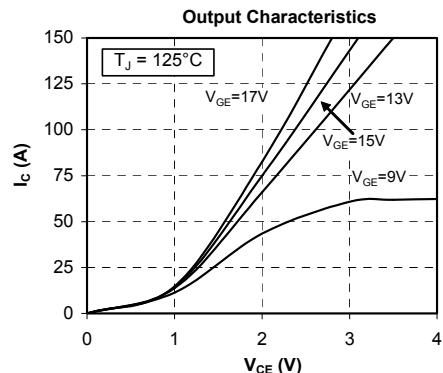
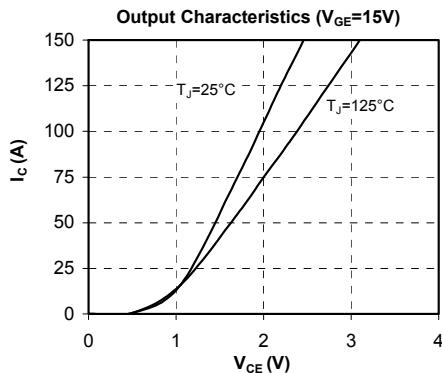
Symbol	Characteristic	Min	Typ	Max	Unit
R_{25}	Resistance @ 25°C		50		$\text{k}\Omega$
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$		3952		K

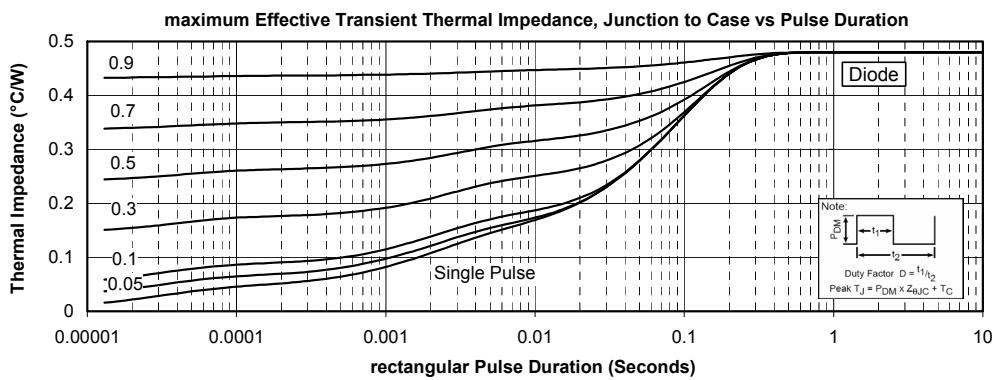
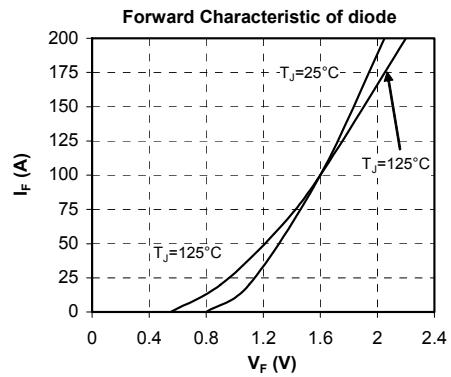
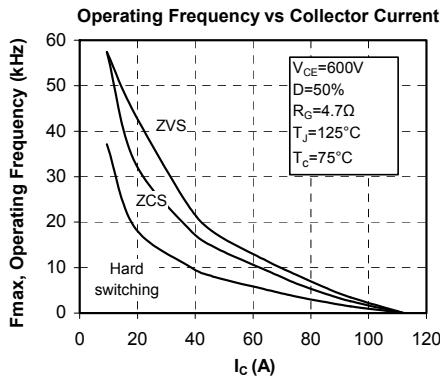
$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]} \quad \begin{array}{l} \text{T: Thermistor temperature} \\ \text{R}_T: \text{Thermistor value at T} \end{array}$$

Thermal and package characteristics

Symbol	Characteristic	Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance	IGBT		0.35	$^{\circ}\text{C/W}$
		Diode		0.48	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz	4000			V
T_J	Operating junction temperature range	-40		150	$^{\circ}\text{C}$
T_{STG}	Storage Temperature Range	-40		125	
T_C	Operating Case Temperature	-40		125	
Torque	Mounting torque	To Heatsink	M5	2.5	4.7
Wt	Package Weight			160	g

SP4 Package outline (dimensions in mm)

 See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

Typical Performance Curve




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